

DDTC (R1-ONLY SERIES) E

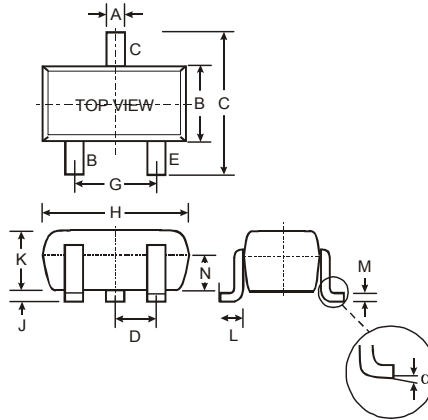
NPN PRE-BIASED SMALL SIGNAL SURFACE MOUNT TRANSISTOR

Features

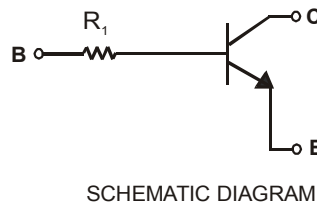
- Epitaxial Planar Die Construction
- Complementary PNP Types Available (DDTA)
- Built-In Biasing Resistor, R1 only
- **Lead Free/RoHS Compliant (Note 2)**
- **"Green" Device (Note 3 and 4)**

Mechanical Data

- Case: SOT-523
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- Terminal Connections: See Diagram
- Marking: Date Code information: See Diagrams & Page 4
- Ordering Information: See Page 4
- Weight: 0.002 grams (approximate)



SOT-523			
Dim	Min	Max	Typ
A	0.15	0.30	0.22
B	0.75	0.85	0.80
C	1.45	1.75	1.60
D	—	—	0.50
G	0.90	1.10	1.00
H	1.50	1.70	1.60
J	0.00	0.10	0.05
K	0.60	0.80	0.75
L	0.10	0.30	0.22
M	0.10	0.20	0.12
N	0.45	0.65	0.50
α	0°	8°	—
All Dimensions in mm			



P/N	R1 (NOM)	Marking
DDTC113TE	1K Ω	N01
DDTC123TE	2.2K Ω	N03
DDTC143TE	4.7K Ω	N07
DDTC114TE	10K Ω	N12
DDTC124TE	22K Ω	N16
DDTC144TE	47K Ω	N19
DDTC115TE	100K Ω	N23
DDTC125TE	200K Ω	N25

Maximum Ratings @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector Base Voltage	V_{CBO}	50	V
Collector-Emitter Voltage	V_{CEO}	50	V
Emitter-Base Voltage	V_{EBO}	5	V
Collector Current	I_C (Max)	100	mA
Power Dissipation	P_d	150	mW
Thermal Resistance, Junction to Ambient Air (Note 1)	$R_{\theta JA}$	833	$^\circ\text{C/W}$
Operating and Storage Temperature Range	T_j, T_{STG}	-55 to +150	$^\circ\text{C}$

- Notes:
1. Mounted on FR4 PC Board with recommended pad layout at <http://www.diodes.com/datasheets/ap02001.pdf>.
 2. No purposefully added lead.
 3. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
 4. Product manufactured with Date Code UO (week 40, 2007) and newer are built with Green Molding Compound. Product manufactured prior to Date Code UO are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.

Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV_{CBO}	50	—	—	V	$I_C = 50\text{mA}$
Collector-Emitter Breakdown Voltage	BV_{CEO}	50	—	—	V	$I_C = 1\text{mA}$
Emitter-Base Breakdown Voltage	BV_{EBO}	5	—	—	V	$I_E = 50\mu\text{A}$
Collector Cutoff Current	I_{CBO}	—	—	0.5	μA	$V_{CB} = 50\text{V}$
Emitter Cutoff Current	I_{EBO}	—	—	0.5	μA	$V_{EB} = 4\text{V}$
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	—	—	0.3	V	$I_C/I_B = 10\text{mA}/1\text{mA}$ DDTC113TE $I_C/I_B = 5\text{mA}/0.5\text{mA}$ DDTC123TE $I_C/I_B = 2.5\text{mA}/.25\text{mA}$ DDTC143TE $I_C/I_B = 1\text{mA}/.1\text{mA}$ DDTC114TE $I_C/I_B = 5\text{mA}/0.5\text{mA}$ DDTC124TE $I_C/I_B = 2.5\text{mA}/.25\text{mA}$ DDTC144TE $I_C/I_B = 1\text{mA}/0.1\text{mA}$ DDTC115TE $I_C/I_B = .5\text{mA}/.05\text{mA}$ DDTC125TE
DC Current Transfer Ratio	h_{FE}	100	250	600	—	$I_C = 1\text{mA}, V_{CE} = 5\text{V}$
Input Resistor (R_1) Tolerance	ΔR_1	-30	—	+30	%	—
Gain-Bandwidth Product*	f_T	—	250	—	MHZ	$V_{CE} = 10\text{V}, I_E = -5\text{mA}, f = 100\text{MHz}$

* Transistor – For Reference Only

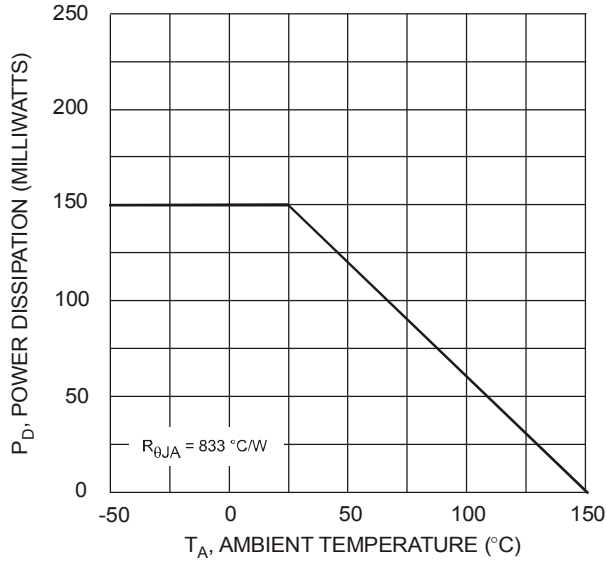


Fig. 1 Derating Curve

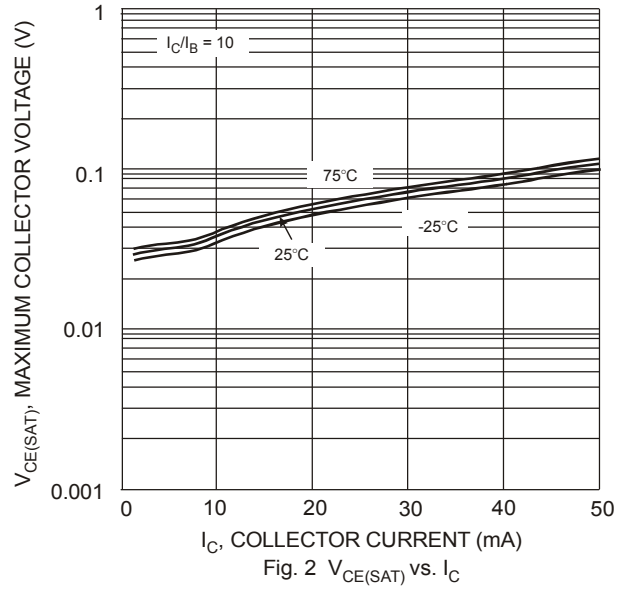


Fig. 2 V_{CE(SAT)} vs. I_C

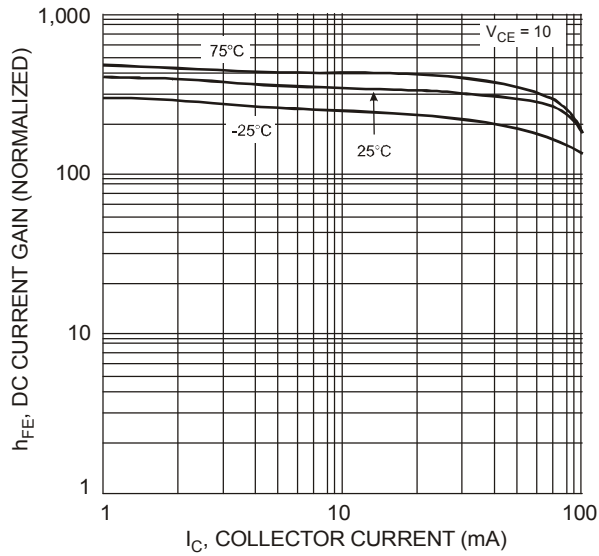


Fig. 3 DC Current Gain

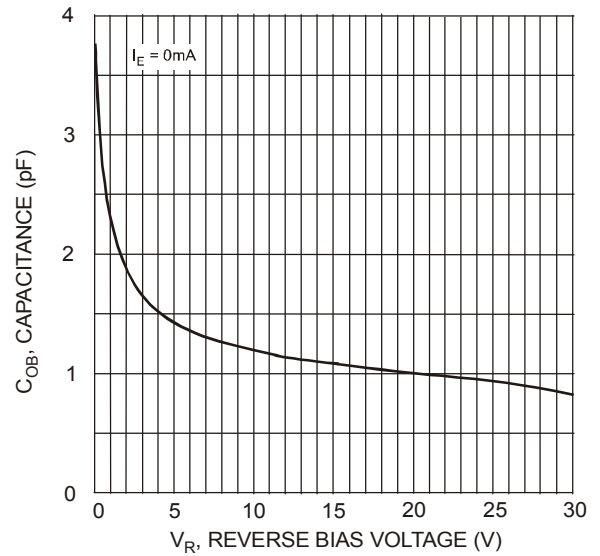


Fig. 4 Output Capacitance

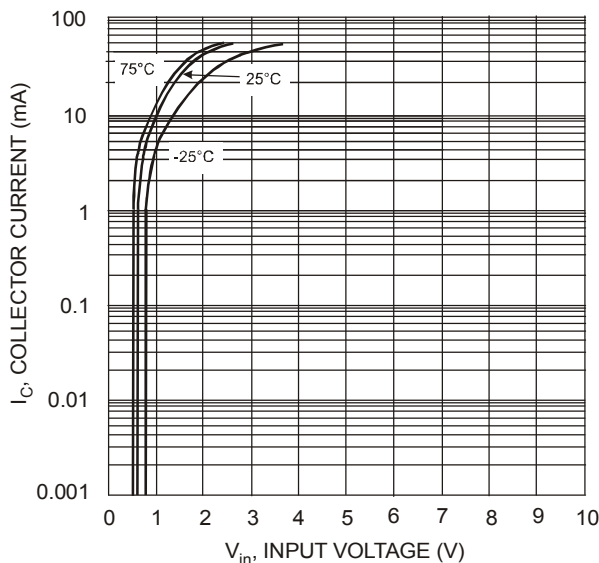


Fig. 5 Collector Current vs. Input Voltage

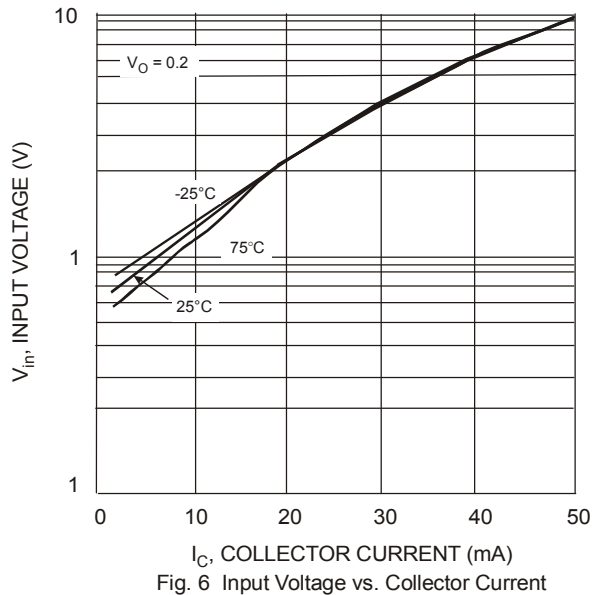


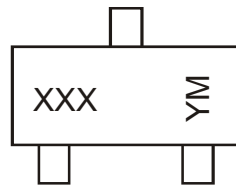
Fig. 6 Input Voltage vs. Collector Current

Ordering Information (Note 5)

Device	Packaging	Shipping
DDTC113TE-7-F	SOT-523	3000/Tape & Reel
DDTC123TE-7-F	SOT-523	3000/Tape & Reel
DDTC143TE-7-F	SOT-523	3000/Tape & Reel
DDTC114TE-7-F	SOT-523	3000/Tape & Reel
DDTC124TE-7-F	SOT-523	3000/Tape & Reel
DDTC144TE-7-F	SOT-523	3000/Tape & Reel
DDTC115TE-7-F	SOT-523	3000/Tape & Reel
DDTC125TE-7-F	SOT-523	3000/Tape & Reel

Notes: 5. For packaging details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

Marking Information



Xxx = Product Type Marking Code
See Page 1 Diagrams
YM = Date Code Marking
Y = Year ex: T = 2006
M = Month ex: 9 = September

Date Code Key

Year	2006	2007	2008	2009	2010	2011	2012
Code	T	U	V	W	X	Y	Z

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

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